

## Product Summary

| $V_{(BR)DSS}$ | $R_{DS(on)TYP}$ | $I_D$ |
|---------------|-----------------|-------|
| 100V          | 3.2mΩ@10V       | 170A  |

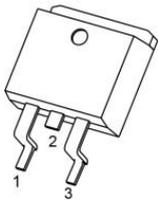
## Feature

- Fast Switching
- Low Gate Charge and R<sub>DS(on)</sub>
- 100% Single Pulse avalanche energy Test

## Applications

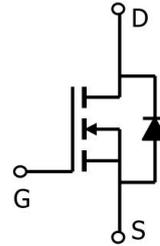
- Power switching application
- DC-DC Converter
- Power Management

## Package

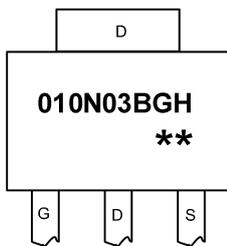


TO-263(G:1 D:2 S:3)

## Circuit diagram



## Marking



010N03BGH : Product code  
 \*\* : Week code

**Absolute maximum ratings (Ta=25°C, unless otherwise noted)**

| Parameter                         | Symbol                            | Rating     | Unit |
|-----------------------------------|-----------------------------------|------------|------|
| Drain source voltage              | V <sub>DS</sub>                   | 100        | V    |
| Gate source voltage               | V <sub>GS</sub>                   | ±20        | V    |
| Continuous drain current(Tc=25°C) | I <sub>D</sub>                    | 170        | A    |
| Pulsed drain current              | I <sub>DM</sub>                   | 680        | A    |
| Power dissipation(Tc=25°C)        | P <sub>D</sub>                    | 220        | W    |
| Single pulsed avalanche energy1)  | E <sub>AS</sub>                   | 180        | mJ   |
| Thermal resistance, junction-case | R <sub>θJC</sub>                  | 0.57       | °C/W |
| Operation and storage temperature | T <sub>stg</sub> , T <sub>j</sub> | -55 to 150 | °C   |

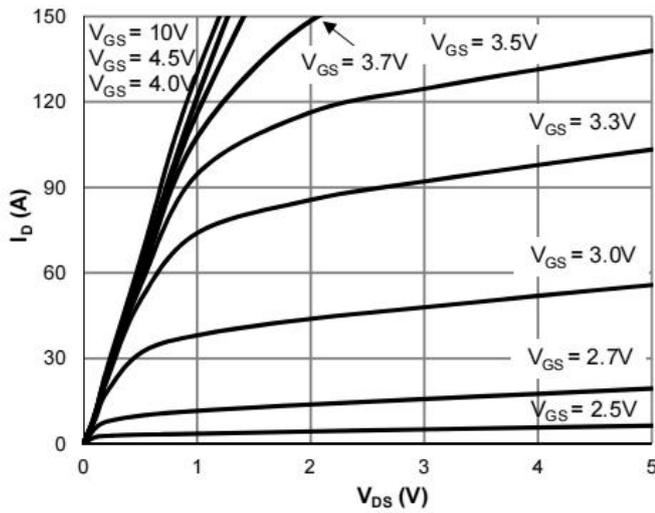
**Electrical characteristics (Ta=25°C, unless otherwise noted)**

| Characteristics                                | Symbol              | Test Condition   | Min | Typ  | Max  | Unit |
|--|---------------------|--|-----|------|------|------|
| <b>Static Characteristics</b>                  |                     |  |     |      |      |      |
| Drain-Source Breakdown Voltage                 | BV <sub>DSS</sub>   | I <sub>D</sub> = 250μA, V <sub>GS</sub> = 0V                                 | 100 | -    | -    | V    |
| Drain Cut-Off Current                          | I <sub>DSS</sub>    | V <sub>DS</sub> = 80V, V <sub>GS</sub> = 0V                                  | -   | -    | 1    | μA   |
| Gate Leakage Current                           | I <sub>GSS</sub>    | V <sub>GS</sub> = ±20V, V <sub>DS</sub> = 0V                                 | -   | -    | ±0.1 |      |
| Gate Threshold Voltage                         | V <sub>GS(th)</sub> | V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250μA                   | 2.0 | 2.7  | 4.0  | V    |
| Drain-Source ON Resistance                     | R <sub>DS(ON)</sub> | V <sub>GS</sub> = 10V, I <sub>D</sub> = 30A                                  | -   | 3.2  | 4.6  | mΩ   |
| <b>Dynamic Characteristics</b>                 |                     |  |     |      |      |      |
| Input Capacitance                              | C <sub>iss</sub>    | V <sub>DS</sub> = 50V, V <sub>GS</sub> = 0V, f = 1.0MHz                      | -   | 6950 | -    | pF   |
| Output Capacitance                             | C <sub>oss</sub>    |  | -   | 1208 | -    |      |
| Reverse Transfer Capacitance                   | C <sub>rss</sub>    |  | -   | 34   | -    |      |
| <b>Switching Characteristics</b>               |                     |  |     |      |      |      |
| Total Gate Charge                              | Q <sub>g</sub>      | V <sub>DS</sub> =50V, V <sub>GS</sub> =10V, I <sub>D</sub> =20A              | -   | 79   | -    | nC   |
| Gate-Source Charge                             | Q <sub>gs</sub>     |  | -   | 12   | -    |      |
| Gate-Drain Charge                              | Q <sub>gd</sub>     |  | -   | 25   | -    |      |
| Turn-On Delay Time                             | t <sub>d(on)</sub>  | V <sub>GS</sub> = 10V, V <sub>DS</sub> = 50V, RL=2.5Ω, R <sub>G</sub> = 6.0Ω | -   | 12   | -    | ns   |
| Rise Time                                      | t <sub>r</sub>      |  | -   | 23   | -    |      |
| Turn-Off Delay Time                            | t <sub>d(off)</sub> |  | -   | 85   | -    |      |
| Fall Time                                      | t <sub>f</sub>      |  | -   | 62   | -    |      |
| <b>Drain-Source Body Diode Characteristics</b> |                     |  |     |      |      |      |
| Source-Drain Diode Forward Voltage             | V <sub>SD</sub>     | I <sub>S</sub> = 1A, V <sub>GS</sub> = 0V                                    | -   | -    | 1.2  | V    |

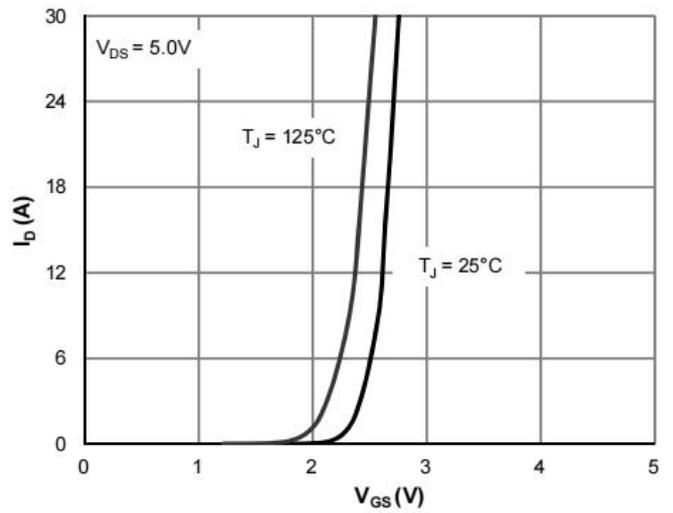
Note:

- E<sub>AS</sub> is tested at starting T<sub>j</sub> = 25°C, V<sub>DD</sub>=50V, V<sub>GS</sub> = 10V, L = 0.1mH, R<sub>g</sub>=25mΩ;

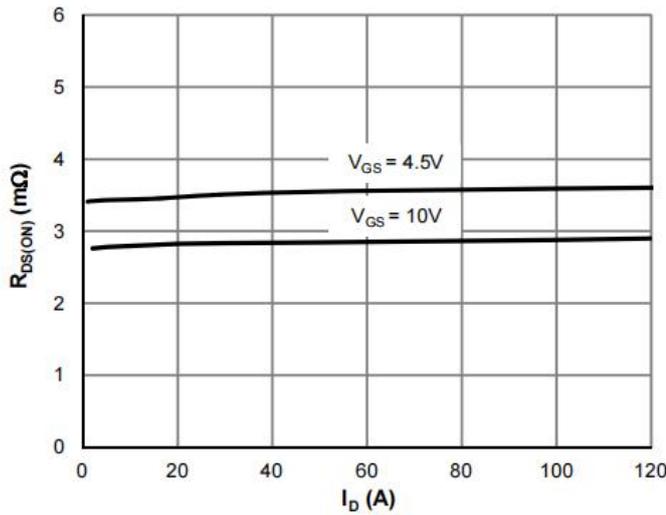
**Typical Characteristics**



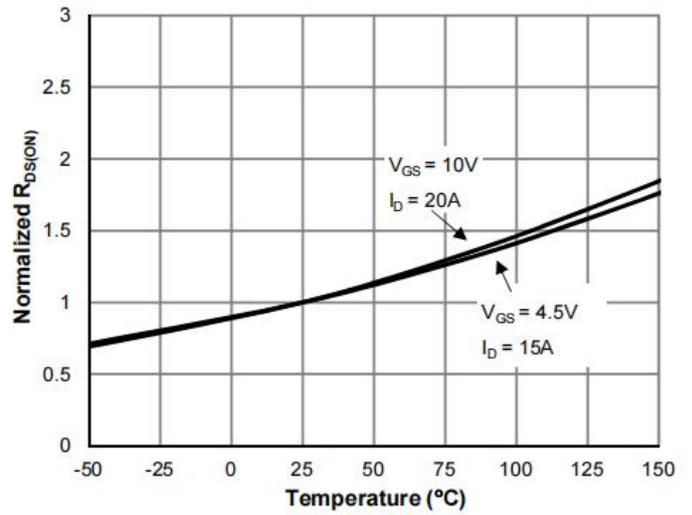
Typical Output Characteristics



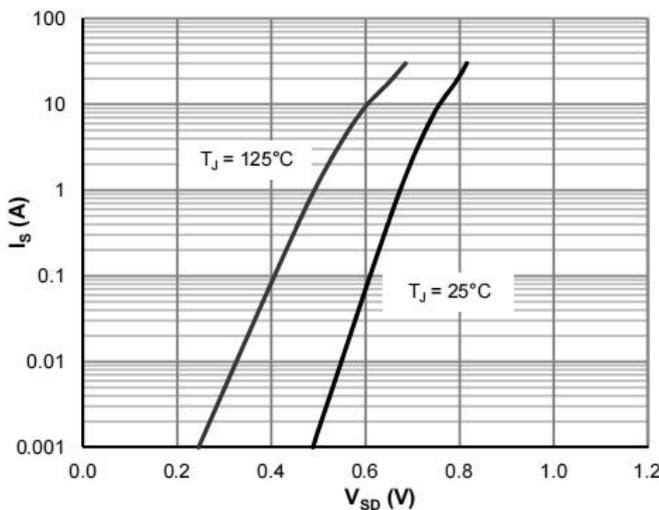
Transfer Characteristics



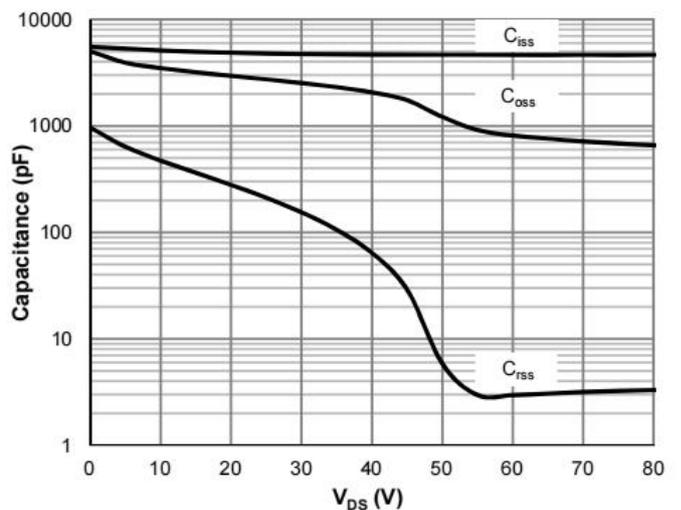
On-Resistance vs. Drain Current



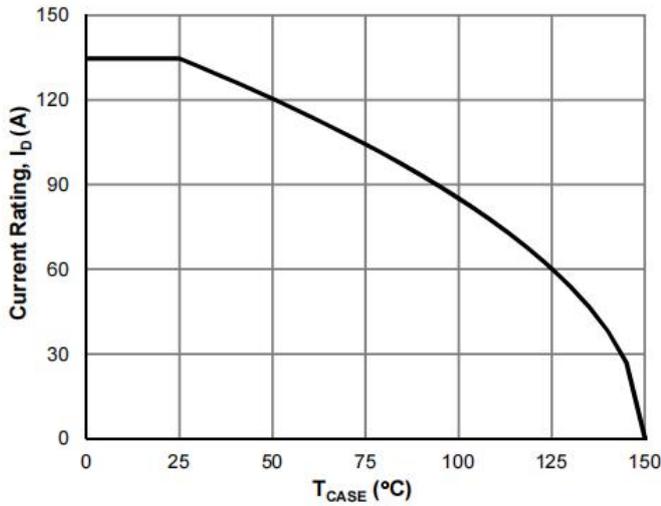
On-Resistance vs. Junction Temperature



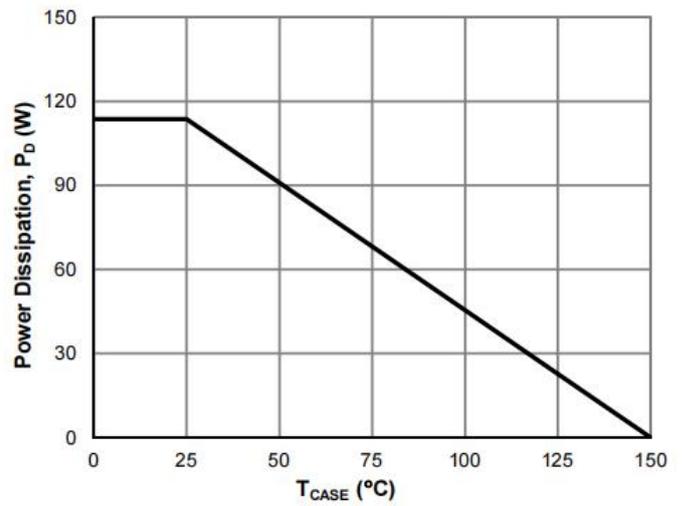
Body-Diode Characteristics



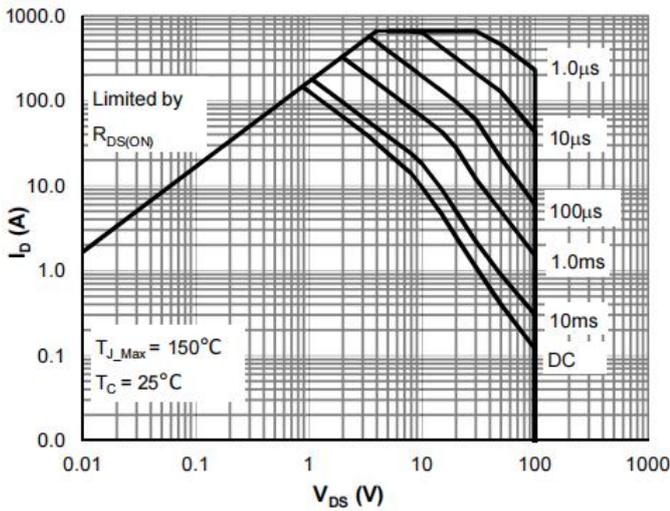
Capacitance Characteristics



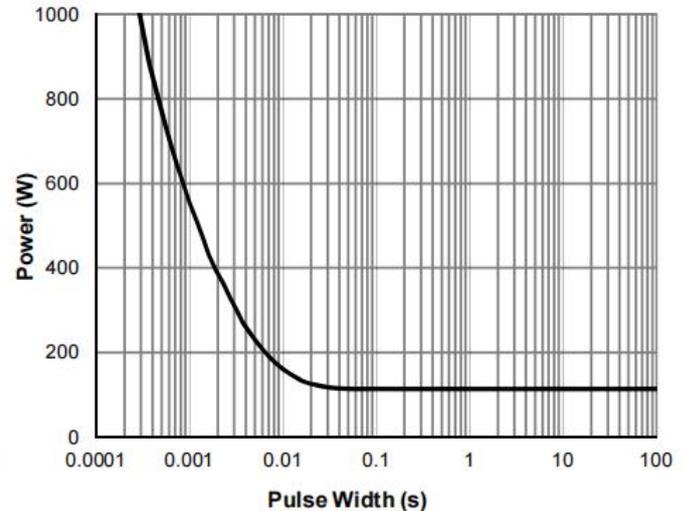
Current De-rating



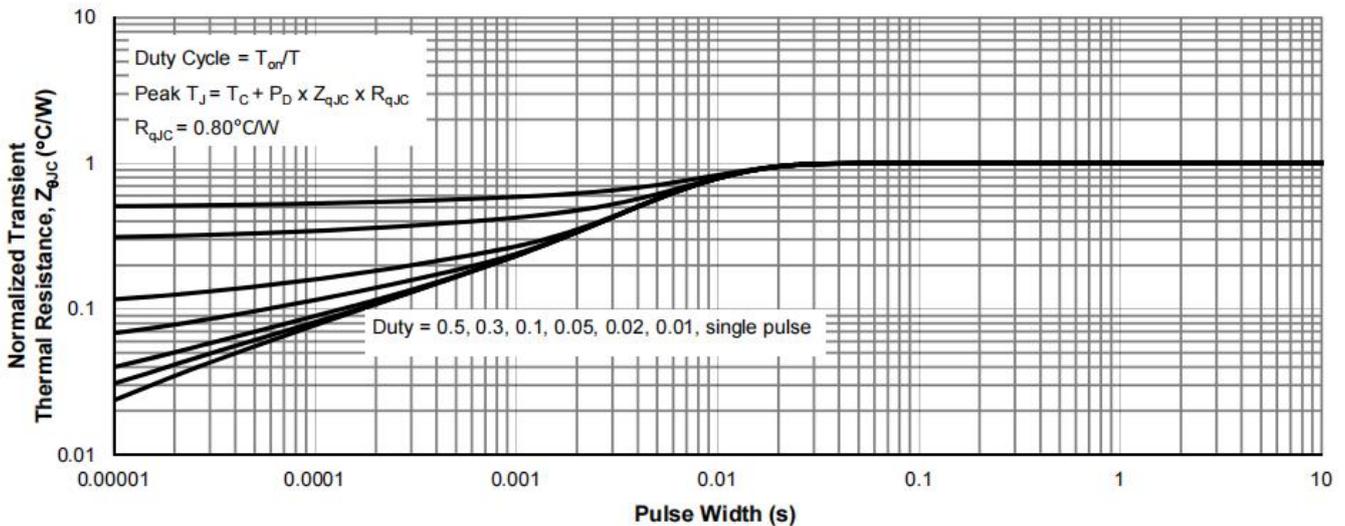
Power De-rating



Maximum Safe Operating Area

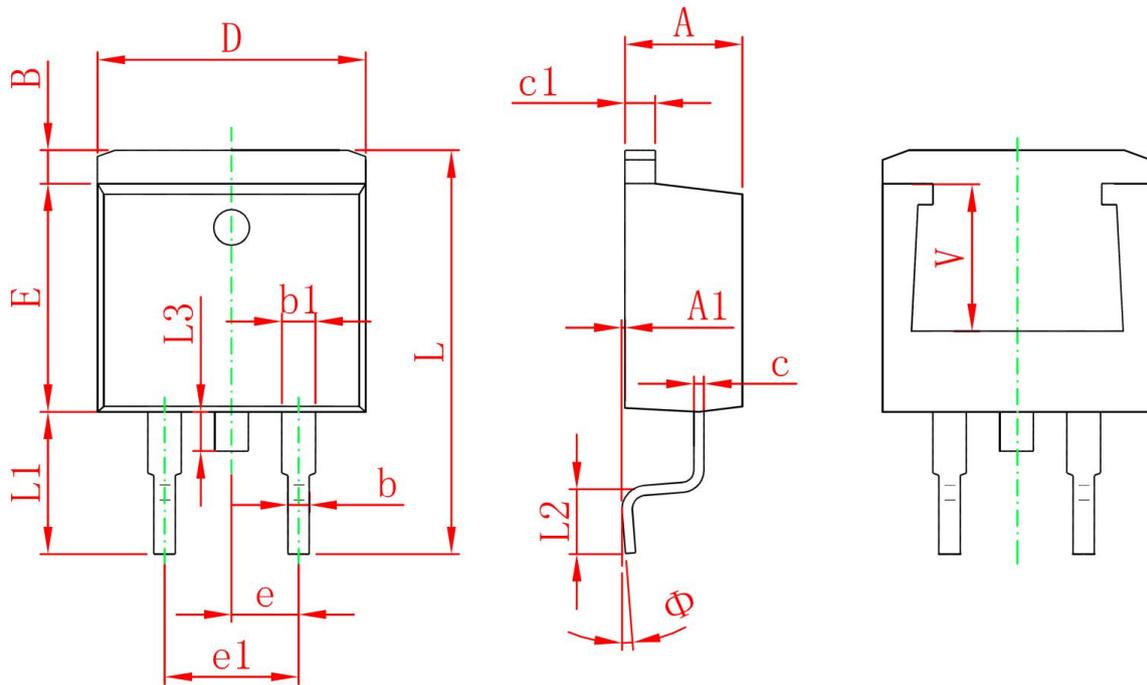


Single Pulse Power Rating, Junction-to-Case



Normalized Maximum Transient Thermal Impedance

**TO-263 Package Information**



| Symbol | Dimensions In Millimeters |        | Dimensions In Inches |       |
|--------|---------------------------|--------|----------------------|-------|
|        | Min.                      | Max.   | Min.                 | Max.  |
| A      | 4.470                     | 4.670  | 0.176                | 0.184 |
| A1     | 0.000                     | 0.150  | 0.000                | 0.006 |
| B      | 1.120                     | 1.420  | 0.044                | 0.056 |
| b      | 0.710                     | 0.910  | 0.028                | 0.036 |
| b1     | 1.170                     | 1.370  | 0.046                | 0.054 |
| c      | 0.310                     | 0.530  | 0.012                | 0.021 |
| c1     | 1.170                     | 1.370  | 0.046                | 0.054 |
| D      | 10.010                    | 10.310 | 0.394                | 0.406 |
| E      | 8.500                     | 8.900  | 0.335                | 0.350 |
| e      | 2.540 TYP.                |        | 0.100 TYP.           |       |
| e1     | 4.980                     | 5.180  | 0.196                | 0.204 |
| L      | 14.940                    | 15.500 | 0.588                | 0.610 |
| L1     | 4.950                     | 5.450  | 0.195                | 0.215 |
| L2     | 2.340                     | 2.740  | 0.092                | 0.108 |
| L3     | 1.300                     | 1.700  | 0.051                | 0.067 |
| $\Phi$ | 0°                        | 8°     | 0°                   | 8°    |
| V      | 5.600 REF.                |        | 0.220 REF.           |       |